

RJH60M6DPQ-A0

600 V - 40 A - IGBT Application: Inverter

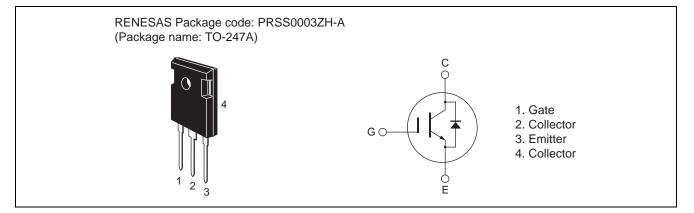
R07DS0537EJ0100 Rev.1.00 Sep 02, 2011

Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.8$ V typ. (at $I_C = 40$ A, $V_{GE} = 15$ V, $Ta = 25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 80$ ns typ. (at $V_{CC} = 300$ V, $V_{GE} = 15$ V, $I_C = 40$ A, $Rg = 5 \Omega$, $Ta = 25^{\circ}C$, inductive load)

Outline



Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	Ι _C	80	A
	Tc = 100°C	Ι _C	40	A
Collector peak current		ic(peak) Note1	160	A
Collector to emitter diode forward current		i _{DF}	50	A
Collector to emitter diode forward peak current		i _{DF} (peak) ^{Note1}	200	A
Collector dissipation		Pc ^{Note2}	260	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	0.48	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	1.07	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	٥C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = 25°C



Electrical Characteristics

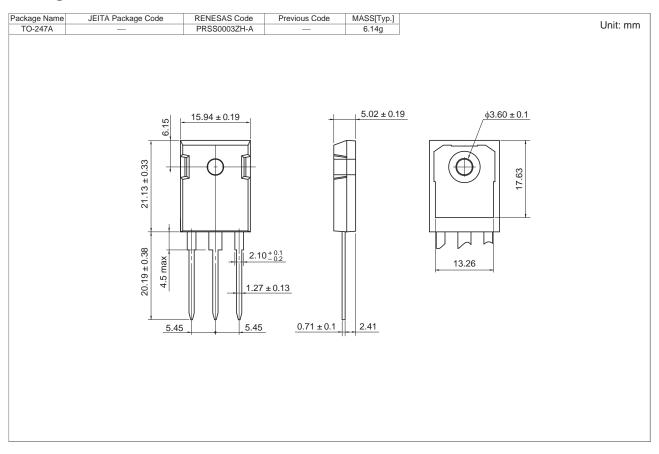
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current	I _{CES} / I _R		_	5	μA	$V_{CE} = 600 \text{ V}, \text{ V}_{GE} = 0$	
/ Diode reverse current							
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$	
Gate to emitter cutoff voltage	V _{GE(off)}	5	_	7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}		1.8	2.3	V	$I_{C} = 40 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}		2.2	_	V	$I_{C} = 80 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies		2500	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	140	_	pF	V _{GE} = 0	
Reveres transfer capacitance	Cres	_	80		pF	f = 1 MHz	
Total gate charge	Qg	_	104		nC	V _{GE} = 15 V V _{CE} = 300 V	
Gate to emitter charge	Qge	_	15	_	nC		
Gate to collector charge	Qgc	_	45	_	nC	$I_{\rm C} = 40 \ {\rm A}$	
Switching time	t _{d(on)}	_	55	_	ns	$V_{CC} = 300 \text{ V}, \text{ V}_{GE} = 15 \text{ V}$	
	tr	_	40	_	ns	I _C = 40 A	
	t _{d(off)}	_	150		ns	$Rg = 5 \Omega$	
	t _f	_	80		ns	(Inductive load)	
Short circuit withstand time	t _{sc}	6	8		μs	Tc = 100 °C	
						$V_{CC} \leq 360$ V, V_{GE} = 15 V	

FRD Forward voltage	VF	—	1.3	1.8	V	$I_F = 40 \text{ A}^{\text{Note3}}$
FRD reverse recovery time	t _{rr}	_	100	_	ns	I _F = 40 A
						di _F /dt = 100 A/µs

Notes: 3. Pulse test.



Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60M6DPQ-A0-T0	240 pcs	Box (Tube)



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